## Modification of photosensitive Polyvinylsilazane for pattering by photolithography

유향임<sup>1</sup>, 김동표<sup>2,3,\*</sup> <sup>1</sup>충남대학교 공업화학과; <sup>2</sup>충남대학교; <sup>3</sup>Center for Ultramicrochemical Process Systems (CUPS), KAIST (dpkim@cnu.ac.kr\*)

A highly photosensitive isocyanatodiacrylate, a precursor for ceramic was synthesized by the reaction of polyvinylsilazane with 1,1-bis(acryloloxyethyl)ethyl isocyanate and the chemicals changes in this reaction were investigated by <sup>1</sup>H-NMR and FT-IR Spectroscopy for the identification of the precursor.

The functionalization of polyvinylsilazane with isocyanatodiacrylate gave a high sensitivity against to UV ray so that the technique of ultravilet nanoimprint lithography was readily available for the one-step fabrication of 3D or multilevel nano/microsturctures with this precursor.

The isocyanatodiacrylate moiety increased the sensitivity in UV-NIL which imprinted the fine structures through single-step multilayered stamping onto a UV-curable resist coated on a substrate with no identifiable damage.